

AD8613/AD8617/AD8619

FEATURES

- Offset voltage: 2.2 mV maximum**
- Low input bias current: 1 pA maximum**
- Single-supply operation: 1.8 V to 5 V**
- Low noise: 22 nV/ $\sqrt{\text{Hz}}$**
- Micropower: 50 μA /amplifier maximum over temperature**
- No phase reversal**
- Unity gain stable**
- Qualified for automotive applications**

APPLICATIONS

- Battery-powered instrumentation**
- Multipole filters**
- Current shunt sense**
- Sensors**
- ADC predrivers**
- DAC drivers/level shifters**
- Low power ASIC input or output amplifiers**

GENERAL DESCRIPTION

The AD8613/AD8617/AD8619 are single, dual, and quad micro-power, rail-to-rail input and output amplifiers that feature low supply current, as well as low input voltage and current noise.

The parts are fully specified to operate from 1.8 V to 5 V single supply, or ± 0.9 V and ± 2.5 V dual supply. The combination of low noise, very low input bias currents, and low power consumption make the AD8613/AD8617/AD8619 especially useful in portable and loop-powered instrumentation.

The ability to swing rail-to-rail at both the input and output enables designers to buffer CMOS ADCs, DACs, ASICs, and other wide output swing devices in low power, single-supply systems.

The AD8613 is available in a 5-lead SC70 package and a 5-lead TSOT-23 package. The AD8617 is available in 8-lead MSOP, 8-lead SOIC, and 8-lead LFCSP packages. The AD8619 is available in 14-lead TSSOP and 14-lead SOIC packages. The AD8617W is qualified for automotive applications and is available in an 8-lead MSOP package and an 8-lead SOIC package.

PIN CONFIGURATIONS



Figure 1. 5-Lead SC70 and 5-Lead TSOT-23

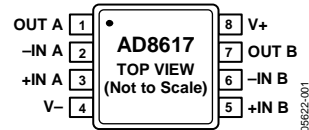
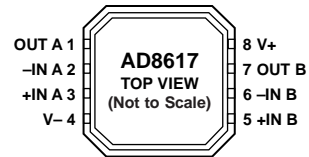


Figure 2. 8-Lead MSOP and 8-Lead SOIC_N



NOTES

1. PIN 4 AND THE EXPOSED PAD MUST BE CONNECTED TO V-.

Figure 3. 8-Lead LFCSP_VD

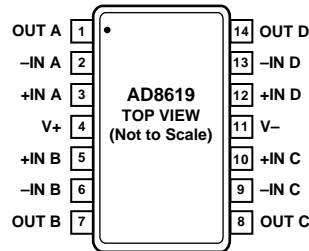


Figure 4. 14-Lead TSSOP

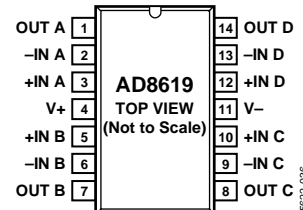


Figure 5. 14-Lead SOIC_N

Rev. E

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TABLE OF CONTENTS

| | | | |
|-------------------------------|---|---|----|
| Features | 1 | Thermal Resistance | 5 |
| Applications..... | 1 | ESD Caution..... | 5 |
| General Description | 1 | Typical Performance Characteristics | 6 |
| Pin Configurations | 1 | Outline Dimensions | 12 |
| Revision History | 2 | Ordering Guide | 15 |
| Specifications..... | 3 | | |
| Absolute Maximum Ratings..... | 5 | | |

REVISION HISTORY

3/10—Rev. D to Rev. E

| | |
|--------------------------------------|----|
| Changes to General Description | 1 |
| Changes to Ordering Guide | 15 |

3/10—Rev. C to Rev. D

| | |
|--------------------------------------|----|
| Changes to General Description | 1 |
| Changes to Ordering Guide | 15 |

10/09—Rev. B to Rev. C

| | |
|---|-----------|
| Added 8-Lead LFCSP Package..... | Universal |
| Changes to Features Section, Figure 2 Caption, General Description Section, and Figure 3 | 1 |
| Changed V_S to V_{SY} Throughout..... | 3 |
| Changes to Input Characteristics, Input Voltage Range Parameter; Dynamic Performance, Settling Time to 0.1% and Phase Margin Parameters; and Noise Performance, Peak-to-Peak Noise Parameter, Table 1 | 3 |
| Changes to Input Characteristics, Input Voltage Range Parameter; Dynamic Performance, Settling Time to 0.1% and Phase Margin Parameters; and Noise Performance, Peak-to-Peak Noise Parameter, Table 2 | 4 |
| Changes to Table 3 and Table 4..... | 5 |
| Changes to Figure 12 to Figure 15..... | 7 |
| Changes to Figure 18 Caption..... | 8 |
| Changes to Figure 30 and Figure 31..... | 10 |
| Updated Outline Dimensions | 12 |
| Added Figure 44; Renumbered Sequentially | 14 |
| Changes to Ordering Guide | 15 |

1/06—Rev. A to Rev. B

| | |
|----------------------------------|-----------|
| Added AD8613 | Universal |
| Changes to Features | 1 |
| Changes to Table 1..... | 3 |
| Changes to Table 2..... | 4 |
| Updated Outline Dimensions | 12 |
| Changes to Ordering Guide | 13 |

10/05—Rev. 0 to Rev. A

| | |
|--|-----------|
| Added AD8619 | Universal |
| Change to Specifications Section | 3 |
| Updated Outline Dimensions | 12 |
| Changes to Ordering Guide | 13 |

9/05—Revision 0: Initial Version

SPECIFICATIONS

Electrical characteristics at $V_{SY} = 5\text{ V}$, $V_{CM} = V_{SY}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 1.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|---|------|----------|-----|------------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $-0.3\text{ V} < V_{CM} < +5.3\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$, $-0.3\text{ V} < V_{CM} < +5.2\text{ V}$ | | 0.4 | 2.2 | mV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 1 | 2.2 | mV |
| AD8613 | | | | 2.5 | 4.5 | $\mu\text{V}/^\circ\text{C}$ |
| Input Bias Current | I_B | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.2 | 1 | $\mu\text{V}/^\circ\text{C}$ |
| | | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ | | | 110 | pA |
| | | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | | 780 | pA |
| Input Offset Current | I_{OS} | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ | | 0.1 | 0.5 | pA |
| | | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | | 50 | pA |
| | | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | | 250 | pA |
| Input Voltage Range | IVR | | 0 | | 5 | V |
| Common-Mode Rejection Ratio | CMRR | $0\text{ V} < V_{CM} < 5\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 95 | | dB |
| Large Signal Voltage Gain | A_{VO} | $R_L = 10\text{ k}\Omega$, $0.5\text{ V} < V_O < 4.5\text{ V}$ | 68 | | | dB |
| Input Capacitance | C_{DIFF} | | | 1.9 | | pF |
| | C_{CM} | | | 2.5 | | pF |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $I_L = 1\text{ mA}$ -40°C to $+125^\circ\text{C}$ | 4.95 | 4.98 | | V |
| | | $I_L = 10\text{ mA}$ -40°C to $+125^\circ\text{C}$ | 4.9 | | | V |
| Output Voltage Low | V_{OL} | $I_L = 1\text{ mA}$ -40°C to $+125^\circ\text{C}$ | 4.50 | | | V |
| | | $I_L = 10\text{ mA}$ -40°C to $+125^\circ\text{C}$ | | 20 | 30 | mV |
| | | $I_L = 10\text{ mA}$ -40°C to $+125^\circ\text{C}$ | | | 50 | mV |
| | | -40°C to $+125^\circ\text{C}$ | | 190 | 275 | mV |
| | | -40°C to $+125^\circ\text{C}$ | | | 335 | mV |
| Short-Circuit Current | I_{SC} | | | ± 80 | | mA |
| Closed-Loop Output Impedance | Z_{OUT} | $f = 10\text{ kHz}$, $A_V = 1$ | | 15 | | Ω |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $1.8\text{ V} < V_{SY} < 5\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 67 | 94 | | dB |
| | | | 64 | | | dB |
| Supply Current/Amplifier | I_{SY} | $V_O = V_{SY}/2$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 38 | | μA |
| | | | | | 50 | μA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 10\text{ k}\Omega$ | | 0.1 | | $\text{V}/\mu\text{s}$ |
| Settling Time to 0.1% | t_s | $G = \pm 1$, $V_{IN} = 2\text{ V}$ step, $C_L = 20\text{ pF}$, $R_L = 1\text{ k}\Omega$ | | 23 | | μs |
| Gain Bandwidth Product | GBP | $R_L = 100\text{ k}\Omega$ | | 400 | | kHz |
| | | $R_L = 10\text{ k}\Omega$ | | 350 | | kHz |
| Phase Margin | ϕ_M | $R_L = 10\text{ k}\Omega$, $R_L = 100\text{ k}\Omega$, $C_L = 20\text{ pF}$ | | 70 | | Degrees |
| NOISE PERFORMANCE | | | | | | |
| Peak-to-Peak Noise | e_n p-p | 0.1 Hz to 10 Hz | | 2.3 | 3.5 | μV |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ | | 25 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| | | $f = 10\text{ kHz}$ | | 22 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 1\text{ kHz}$ | | 0.05 | | $\text{pA}/\sqrt{\text{Hz}}$ |

AD8613/AD8617/AD8619

Electrical characteristics at $V_{SY} = 1.8\text{ V}$, $V_{CM} = V_{SY}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 2.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|--|-------------|------------|----------|--|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $-0.3\text{ V} < V_{CM} < +1.9\text{ V}$ $-0.3\text{ V} < V_{CM} < +1.8\text{ V}; -40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.4 | 2.2 | mV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 1 | 8.5 | $\mu\text{V}/^\circ\text{C}$ |
| AD8613 | | | | 3.7 | 9.0 | $\mu\text{V}/^\circ\text{C}$ |
| Input Bias Current | I_B | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.2 | 1 | pA |
| | | | | | 110 | pA |
| Input Offset Current | I_{OS} | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 0.1 | 0.5 | pA |
| | | | | | 50 | pA |
| Input Voltage Range | IVR | | 0 | | 1.8 | V |
| Common-Mode Rejection Ratio | CMRR | $0\text{ V} < V_{CM} < 1.8\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | 58 | 86 | | dB |
| | | | 55 | | | dB |
| Large Signal Voltage Gain | A_{VO} | $R_L = 10\text{ k}\Omega$, $0.5\text{ V} < V_O < 1.3\text{ V}$ | 85 | 1000 | | V/mV |
| Input Capacitance | C_{DIFF} C_{CM} | | | 2.1 | | pF |
| | | | | 3.8 | | pF |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $I_L = 1\text{ mA}$ -40°C to $+125^\circ\text{C}$ | 1.65 1.6 | 1.73 | | V V |
| Output Voltage Low | V_{OL} | $I_L = 1\text{ mA}$ -40°C to $+125^\circ\text{C}$ | | 44 | 60 80 | mV mV |
| Short-Circuit Current | I_{SC} | | | ± 7 | | mA |
| Closed-Loop Output Impedance | Z_{OUT} | $f = 10\text{ kHz}$, $A_V = 1$ | | 15 | | Ω |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $1.8\text{ V} < V_S < 5\text{ V}$ | 67 | 94 | | dB |
| Supply Current/Amplifier | I_{SY} | $V_O = V_{SY}/2$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 38 | 50 | μA μA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 10\text{ k}\Omega$ | | 0.1 | | V/ μs |
| Settling Time to 0.1% | t_S | $G = \pm 1$, $V_{IN} = 1\text{ V}$ step, $C_L = 20\text{ pF}$, $R_L = 1\text{ k}\Omega$ | | 6.5 | | μs |
| Gain Bandwidth Product | GBP | $R_L = 100\text{ k}\Omega$ $R_L = 10\text{ k}\Omega$ | | 400 350 | | kHz kHz |
| Phase Margin | ϕ_M | $R_L = 10\text{ k}\Omega$, $R_L = 100\text{ k}\Omega$, $C_L = 20\text{ pF}$ | | 70 | | Degrees |
| NOISE PERFORMANCE | | | | | | |
| Peak-to-Peak Noise | e_n p-p | 0.1 Hz to 10 Hz | | 2.3 | 3.5 | μV |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ $f = 10\text{ kHz}$ | | 25 22 | | $\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 1\text{ kHz}$ | | 0.05 | | $\text{pA}/\sqrt{\text{Hz}}$ |

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

| Parameter | Rating |
|--------------------------------------|--|
| Supply Voltage | 6 V |
| Input Voltage | $V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ |
| Input Current | $\pm 10\text{ mA}$ |
| Differential Input Voltage | $\pm 6\text{ V}$ |
| Output Short-Circuit Duration to GND | Indefinite |
| Storage Temperature Range | -65°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 60 sec) | 300°C |
| Operating Temperature Range | -40°C to $+125^\circ\text{C}$ |
| Junction Temperature Range | -65°C to $+150^\circ\text{C}$ |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 4. Thermal Characteristics

| Package Type | θ_{JA} | θ_{JC} | Unit |
|--------------------------|---------------|---------------|---------------------------|
| 5-Lead TSOT-23 (UJ-5) | 207 | 61 | $^\circ\text{C}/\text{W}$ |
| 5-Lead SC70 (KS-5) | 376 | 126 | $^\circ\text{C}/\text{W}$ |
| 8-Lead MSOP (RM-8) | 210 | 45 | $^\circ\text{C}/\text{W}$ |
| 8-Lead SOIC_N (R-8) | 158 | 43 | $^\circ\text{C}/\text{W}$ |
| 8-Lead LFCSP_VD (CP-8-9) | 81 | 20 | $^\circ\text{C}/\text{W}$ |
| 14-Lead SOIC_N (R-14) | 120 | 36 | $^\circ\text{C}/\text{W}$ |
| 14-Lead TSSOP (RU-14) | 180 | 35 | $^\circ\text{C}/\text{W}$ |

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

$V_{SY} = 5\text{ V}$ or $\pm 2.5\text{ V}$, unless otherwise noted.



Figure 6. Input Offset Voltage Distribution

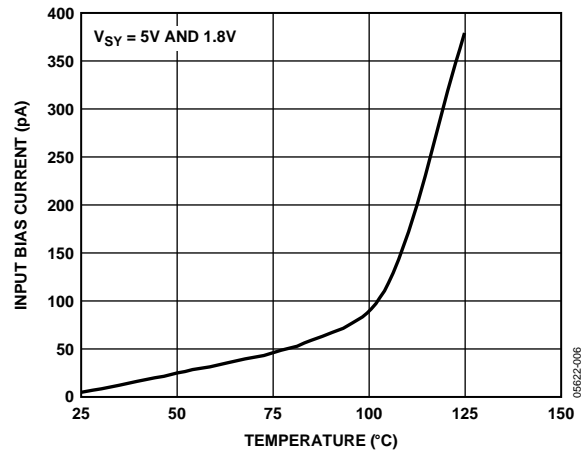


Figure 9. Input Bias Current vs. Temperature



Figure 7. Input Offset Voltage Drift Distribution

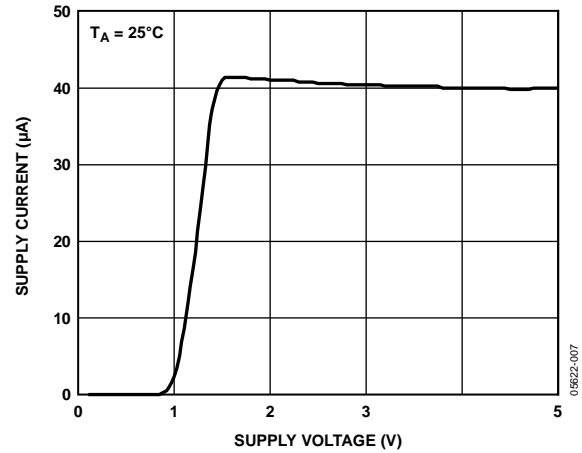


Figure 10. Supply Current vs. Supply Voltage



Figure 8. Input Offset Voltage vs. Input Common-Mode Voltage

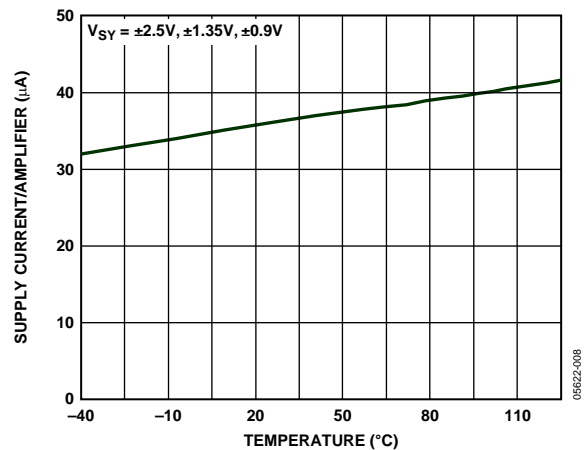


Figure 11. Supply Current vs. Temperature



Figure 12. Output Voltage to Supply Rail vs. Load Current



Figure 15. Open-Loop Gain and Phase vs. Frequency



Figure 13. Output Voltage to Supply Rail vs. Temperature ($I_L = 1 \text{ mA}$)



Figure 16. CMRR vs. Frequency



Figure 14. Output Voltage to Supply Rail vs. Temperature ($I_L = 10 \text{ mA}$)



Figure 17. PSRR vs. Frequency



Figure 18. Output Impedance vs. Frequency



Figure 21. Large Signal Transient Response



Figure 19. Small Signal Overshoot vs. Load Capacitance

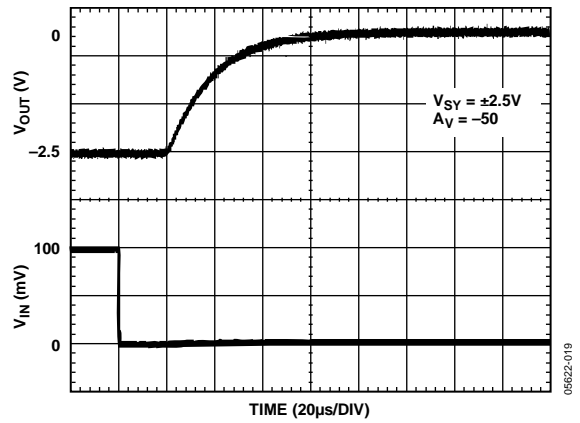


Figure 22. Positive Overload Recovery



Figure 20. Small Signal Transient Response



Figure 23. Negative Overload Recovery



Figure 24. No Phase Reversal



Figure 26. Voltage Noise Density



Figure 25. 0.1 Hz to 10 Hz Input Voltage Noise



Figure 27. Channel Separation

AD8613/AD8617/AD8619

$V_{SY} = 1.8\text{ V}$ or $\pm 0.9\text{ V}$, unless otherwise noted.



Figure 28. Input Offset Voltage Distribution



Figure 31. Output Voltage to Supply Rail vs. Temperature ($I_L = 1\text{ mA}$)



Figure 29. Input Offset Voltage vs. Input Common-Mode Voltage



Figure 32. CMRR vs. Frequency



Figure 30. Output Voltage to Supply Rail vs. Load Current



Figure 33. PSRR vs. Frequency



Figure 34. Small Signal Overshoot vs. Load Capacitance



Figure 36. 0.1 Hz to 10 Hz Input Voltage Noise

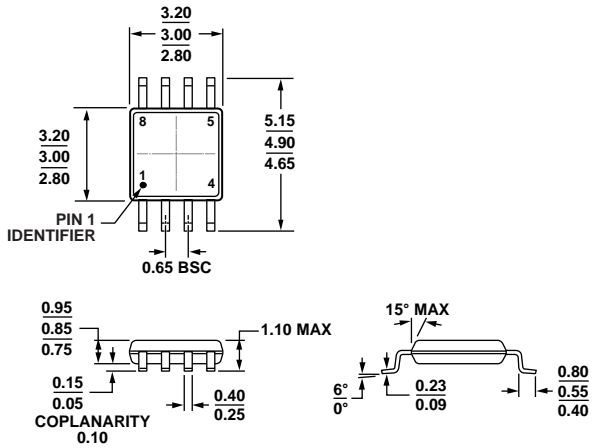


Figure 35. Large Signal Transient Response



Figure 37. Voltage Noise Density

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-AA
 Figure 38. 8-Lead Mini Small Outline Package [MSOP] (RM-8)
 Dimensions shown in millimeters

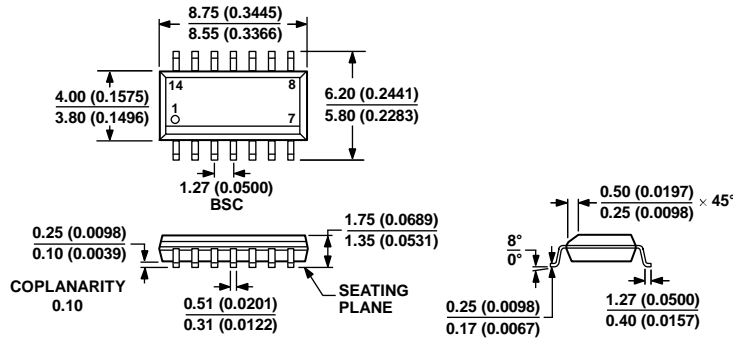
100709-B



COMPLIANT TO JEDEC STANDARDS MS-012-AA
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 39. 8-Lead Standard Small Outline Package [SOIC_N] Narrow Body (R-8)
 Dimensions shown in millimeters and (inches)

012407-A



COMPLIANT TO JEDEC STANDARDS MS-012-AB
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 40. 14-Lead Standard Small Outline Package [SOIC_N] Narrow Body (R-14)
 Dimensions shown in millimeters and (inches)

060606-A

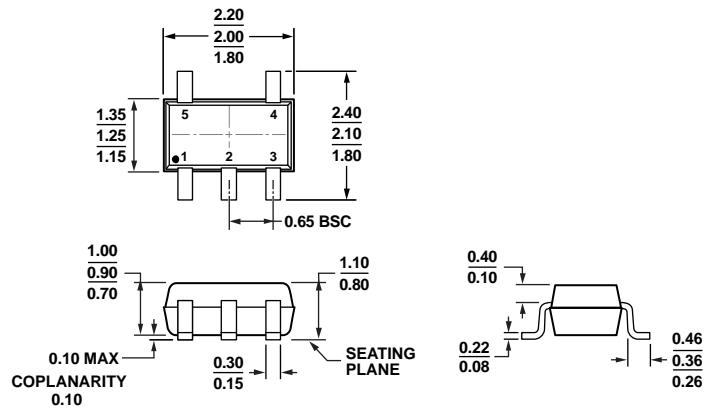


COMPLIANT TO JEDEC STANDARDS MO-153-AB-1

Figure 41. 14-Lead Thin Shrink Small Outline Package [TSSOP] (RU-14)

Dimensions shown in millimeters

061908-A



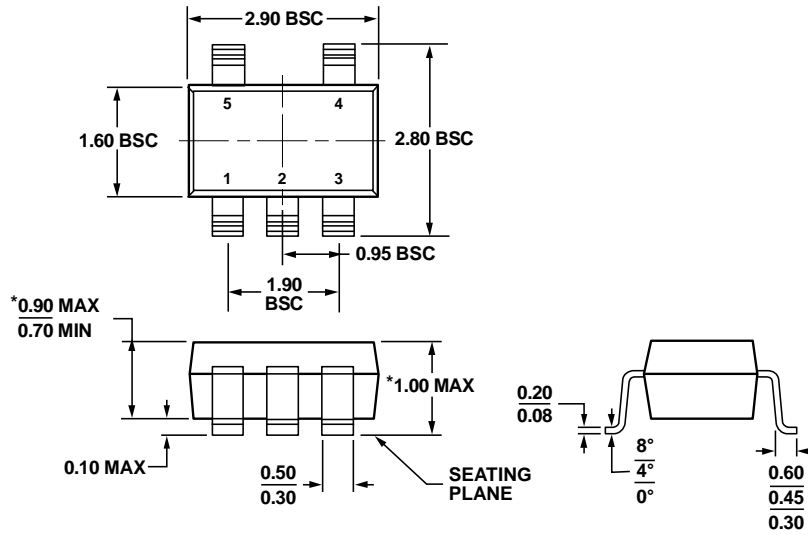
COMPLIANT TO JEDEC STANDARDS MO-203-AA

Figure 42. 5-Lead Thin Shrink Small Outline Transistor Package [SC70] (KS-5)

Dimensions shown in millimeters

072809-A

AD8613/AD8617/AD8619



*COMPLIANT TO JEDEC STANDARDS MO-193-AB WITH THE EXCEPTION OF PACKAGE HEIGHT AND THICKNESS.

Figure 43. 5-Lead Thin Small Outline Transistor Package [TSOT-23] (UJ-5)

Dimensions shown in millimeters

100708-A



Figure 44. 8-Lead Lead Frame Chip Scale Package [LFCSP_VD]

3 mm × 3 mm Body, Very Thin, Dual Lead (CP-8-9)

Dimensions shown in millimeters

0519809-A

ORDERING GUIDE

| Model ¹ | Temperature Range | Package Description | Package Option | Branding |
|-------------------------------|-------------------|---------------------|----------------|----------|
| AD8613AKSZ-R2 | -40°C to +125°C | 5-Lead SC70 | KS-5 | A0Y |
| AD8613AKSZ-REEL | -40°C to +125°C | 5-Lead SC70 | KS-5 | A0Y |
| AD8613AKSZ-REEL7 | -40°C to +125°C | 5-Lead SC70 | KS-5 | A0Y |
| AD8613AUJZ-R2 | -40°C to +125°C | 5-Lead TSOT-23 | UJ-5 | A0Y |
| AD8613AUJZ-REEL | -40°C to +125°C | 5-Lead TSOT-23 | UJ-5 | A0Y |
| AD8613AUJZ-REEL7 | -40°C to +125°C | 5-Lead TSOT-23 | UJ-5 | A0Y |
| AD8617ACPZ-R2 | -40°C to +125°C | 8-Lead LFCSP_VD | CP-8-9 | A0T |
| AD8617ACPZ-R7 | -40°C to +125°C | 8-Lead LFCSP_VD | CP-8-9 | A0T |
| AD8617ACPZ-RL | -40°C to +125°C | 8-Lead LFCSP_VD | CP-8-9 | A0T |
| AD8617ARMZ | -40°C to +125°C | 8-Lead MSOP | RM-8 | A0T |
| AD8617ARMZ-REEL | -40°C to +125°C | 8-Lead MSOP | RM-8 | A0T |
| AD8617ARZ | -40°C to +125°C | 8-Lead SOIC_N | R-8 | |
| AD8617ARZ-REEL | -40°C to +125°C | 8-Lead SOIC_N | R-8 | |
| AD8617ARZ-REEL7 | -40°C to +125°C | 8-Lead SOIC_N | R-8 | |
| AD8617WARMZ-REEL ² | -40°C to +125°C | 8-Lead MSOP | RM-8 | A23 |
| AD8617WARZ-R7 ² | -40°C to +125°C | 8-Lead SOIC_N | R-8 | |
| AD8617WARZ-RL ² | -40°C to +125°C | 8-Lead SOIC_N | R-8 | |
| AD8619ARUZ | -40°C to +125°C | 14-Lead TSSOP | RU-14 | |
| AD8619ARUZ-REEL | -40°C to +125°C | 14-Lead TSSOP | RU-14 | |
| AD8619ARZ | -40°C to +125°C | 14-Lead SOIC_N | R-14 | |
| AD8619ARZ-REEL | -40°C to +125°C | 14-Lead SOIC_N | R-14 | |
| AD8619ARZ-REEL7 | -40°C to +125°C | 14-Lead SOIC_N | R-14 | |

¹ Z = RoHS Compliant Part.² Qualified for automotive applications.

NOTES

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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